INTEGRATED CIRCUITS

DATA SHEET

74LVC1G125Bus buffer/line driver; 3-state

Product specification Supersedes data of 2002 Nov 18





Bus buffer/line driver; 3-state

74LVC1G125

FEATURES

- Wide supply voltage range from 1.65 V to 5.5 V
- · High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V).
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- · Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- · Multiple package options
- · ESD protection:
 - HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.

DESCRIPTION

The 74LVC1G125 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using I_{off} . The I_{off} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC1G125 provides one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input ($\overline{\text{OE}}$). A HIGH level at pin $\overline{\text{OE}}$ causes the output to assume a high-impedance OFF-state.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = $t_f \le 2.5$ ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	propagation delay input A to output Y	$V_{CC} = 1.8 \text{ V}; C_L = 30 \text{ pF}; R_L = 1 \text{ k}\Omega$	3.3	ns
		$V_{CC} = 2.5 \text{ V}; C_L = 30 \text{ pF}; R_L = 500 \Omega$	2.2	ns
		$V_{CC} = 2.7 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.5	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.1	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	1.7	ns
C _I	input capacitance		5	pF
C _{PD}	power dissipation capacitance per buffer	output enabled; notes 1 and 2	25	pF
		output disabled; notes 1 and 2	6	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

Bus buffer/line driver; 3-state

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FUNCTION TABLE

See note 1.

INF	OUTPUT	
ŌĒ	ŌE A	
L	L	L
L	Н	Н
Н	X	Z

Note

1. H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

ORDERING INFORMATION

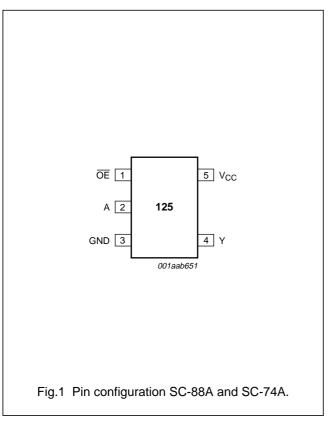
	PACKAGE								
TYPE NUMBER	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING			
74LVC1G125GW	-40 °C to +125 °C	5	SC-88A	plastic	SOT353	VM			
74LVC1G125GV	-40 °C to +125 °C	5	SC-74A	plastic	SOT753	V25			
74LVC1G125GM	–40 °C to +125 °C	6	XSON6	plastic	SOT886	VM			

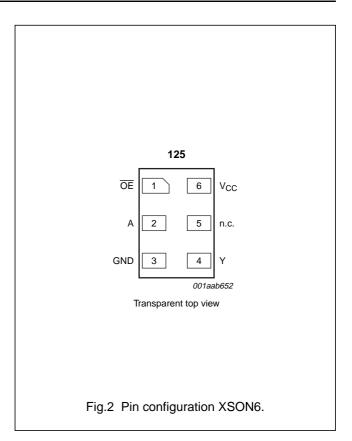
PINNING

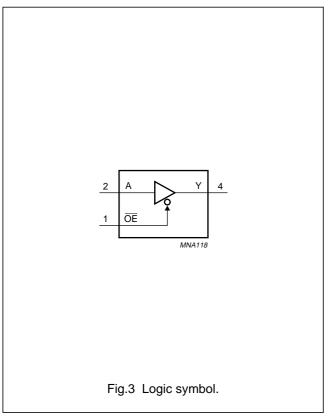
PIN SC-88A; SC-74A	PIN XSON6	SYMBOL	DESCRIPTION
1	1	ŌĒ	output enable input
2	2	А	data input A
3	3	GND	ground (0 V)
4	4	Υ	data output Y
-	5	n.c.	not connected
5	6	V _{CC}	supply voltage

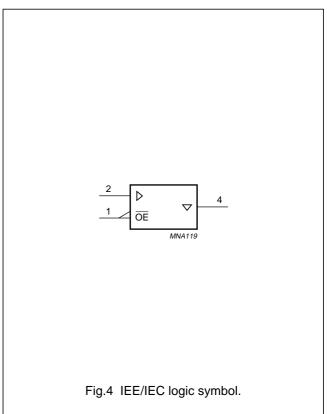
Bus buffer/line driver; 3-state

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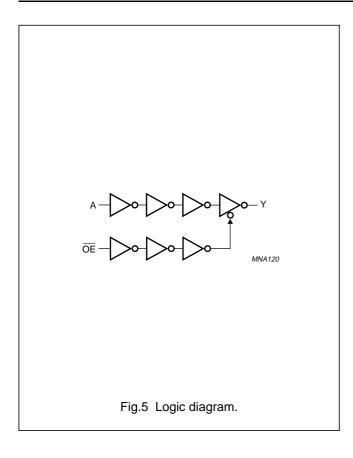






Bus buffer/line driver; 3-state

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Bus buffer/line driver; 3-state

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	V _{CC} = 1.65 V to 5.5 V; enable mode	0	V _{CC}	V
		V _{CC} = 1.65 V to 5.5 V; disable mode	0	5.5	V
		V _{CC} = 0 V; Power-down mode	0	5.5	٧
T _{amb}	operating ambient temperature		-40	+125	°C
t _r , t _f	input rise and fall times	V _{CC} = 1.65 V to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 V to 5.5 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input diode current	V _I < 0 V	_	-50	mA
V _I	input voltage	note 1	-0.5	+6.5	V
I _{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$ V	_	±50	mA
Vo	output voltage	enable mode; notes 1 and 2	-0.5	V _{CC} + 0.5	V
		disable mode; notes 1 and 2	-0.5	+6.5	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
Io	output source or sink current	$V_O = 0 \text{ V to } V_{CC}$	_	±50	mA
I _{CC} , I _{GND}	V _{CC} or GND current		_	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	_	250	mW

Notes

- 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2. When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		RAINI	TYP. ⁽¹⁾	MAY	LINUT
STWIBUL	PARAMETER	OTHER	V _{CC} (V)	MIN.	117.	MAX.	UNIT
T _{amb} = -40	°C to +85 °C				•		
V _{IH}	HIGH-level input		1.65 to 1.95	0.65 × V _{CC}	_	_	V
	voltage		2.3 to 2.7	1.7	_	_	V
			2.7 to 3.6	2.0	_	_	V
			4.5 to 5.5	$0.7 \times V_{CC}$	_	_	V
V _{IL}	LOW-level input		1.65 to 1.95	_	_	$0.35 \times V_{CC}$	V
	voltage		2.3 to 2.7	_	_	0.7	V
			2.7 to 3.6	_	_	0.8	V
			4.5 to 5.5	_	_	$0.3 \times V_{CC}$	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}					
	output voltage	I _O = 100 μA	1.65 to 5.5	_	_	0.1	V
		I _O = 4 mA	1.65	_	_	0.45	V
		I _O = 8 mA	2.3	_	_	0.3	V
		I _O = 12 mA	2.7	_	_	0.4	V
		I _O = 24 mA	3.0	_	_	0.55	V
		I _O = 32 mA	4.5	_	_	0.55	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}					
	output voltage	$I_{O} = -100 \mu A$	1.65 to 5.5	V _{CC} – 0.1	_	_	V
		$I_O = -4 \text{ mA}$	1.65	1.2	_	_	V
		$I_O = -8 \text{ mA}$	2.3	1.9	_	_	V
		$I_0 = -12 \text{ mA}$	2.7	2.2	_	_	V
		I _O = -24 mA	3.0	2.7	_	_	V
		$I_{O} = -32 \text{ mA}$	4.5	3.8	_	_	V
ILI	input leakage current	V _I = 5.5 V or GND	5.5	_	±0.1	±5	μΑ
l _{OZ}	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	5.5	_	±0.1	±10	μΑ
l _{off}	power OFF leakage current	V_I or $V_O = 5.5 \text{ V}$	0	-	±0.1	±10	μΑ
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A	5.5	-	0.1	10	μΑ
Δl _{CC}	additional quiescent supply current per pin	$V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0 \text{ A}$	2.3 to 5.5	-	5	500	μА

Bus buffer/line driver; 3-state

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SYMBOL	DADAMETER	TEST CONDITIONS		RAINI	T)(D (1)	NA A V	LINUT	
SYMBOL PARAMETER		OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	UNIT	
T _{amb} = -40	°C to +125 °C		1	1	1	'		
V _{IH}	HIGH-level input		1.65 to 1.95	0.65 × V _{CC}	_	_	V	
	voltage		2.3 to 2.7	1.7	_	_	V	
			2.7 to 3.6	2.0	_	_	V	
			4.5 to 5.5	$0.7 \times V_{CC}$	_	_	V	
V _{IL}	LOW-level input		1.65 to 1.95	_	_	$0.35 \times V_{CC}$	V	
	voltage		2.3 to 2.7	_	_	0.7	V	
			2.7 to 3.6	_	_	0.8	V	
			4.5 to 5.5	_	_	$0.3 \times V_{CC}$	V	
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}						
	output voltage	I _O = 100 μA	1.65 to 5.5	_	_	0.1	V	
		$I_O = 4 \text{ mA}$	1.65	_	_	0.70	V	
		$I_O = 8 \text{ mA}$	2.3	_	_	0.45	V	
		I _O = 12 mA	2.7	_	_	0.60	V	
		I _O = 24 mA	3.0	_	_	0.80	V	
		I _O = 32 mA	4.5	_	_	0.80	V	
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}						
	output voltage	$I_{O} = -100 \mu A$	1.65 to 5.5	V _{CC} – 0.1	_	_	V	
		$I_O = -4 \text{ mA}$	1.65	0.95	_	_	V	
		$I_O = -8 \text{ mA}$	2.3	1.7	_	_	V	
		I _O = -12 mA	2.7	1.9	_	_	V	
		I _O = -24 mA	3.0	2.0	_	_	V	
		$I_{O} = -32 \text{ mA}$	4.5	3.4	_	_	V	
I _{LI}	input leakage current	V _I = 5.5 V or GND	5.5	-	_	±100	μΑ	
l _{OZ}	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	5.5	_	_	±200	μΑ	
I _{off}	power OFF leakage current	V_I or $V_O = 5.5 \text{ V}$	0	-	_	±200	μΑ	
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A	5.5	-	_	200	μΑ	
Δl _{CC}	additional quiescent supply current per pin	$V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0 \text{ A}$	2.3 to 5.5	_	_	5000	μΑ	

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 $^{\circ}C.$

Bus buffer/line driver; 3-state

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AC CHARACTERISTICS

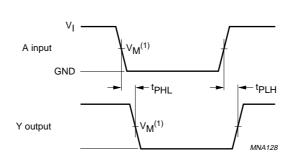
GND = 0 V; $t_r = t_f \le 2.0$ ns.

0)/MD01	SYMBOL PARAMETER	TEST CON	DITIONS		TVD	MAY	
SYMBOL		WAVEFORMS	V _{CC} (V)	MIN.	TYP.	MAX.	UNIT
T _{amb} = -40) °C to +85 °C		1	-1	1	-	
t _{PHL} /t _{PLH}	propagation delay	see Figs 6 and 8	1.65 to 1.95	1.0	3.3	8.0	ns
	A, B to Y		2.3 to 2.7	0.5	2.2	5.5	ns
			2.7	0.5	2.5	5.5	ns
			3.0 to 3.6	0.5	2.1	4.5	ns
			4.5 to 5.5	0.5	1.7	4.0	ns
t _{PZH} /t _{PZL}	3-state output enable	see Figs 7 and 8	1.65 to 1.95	1.0	4.1	9.4	ns
	time input OE to Y		2.3 to 2.7	0.5	2.8	6.6	ns
			2.7	0.5	3.3	6.6	ns
			3.0 to 3.6	0.5	2.4	5.3	ns
			4.5 to 5.5	0.5	2.1	5.0	ns
t _{PHZ} /t _{PLZ}	3-state output disable	see Figs 7 and 8	1.65 to 1.95	1.0	4.3	9.2	ns
	time input OE to Y		2.3 to 2.7	0.5	2.7	5.0	ns
			2.7	0.5	3.0	5.0	ns
			3.0 to 3.6	0.5	3.1	5.0	ns
			4.5 to 5.5	0.5	2.2	4.2	ns
T _{amb} = -40) °C to +125 °C			'	•	'	
t _{PHL} /t _{PLH}	propagation delay	see Figs 6 and 8	1.65 to 1.95	1.0	_	10.5	ns
	A, B to Y		2.3 to 2.7	0.5	_	7	ns
			2.7	0.5	_	7	ns
			3.0 to 3.6	0.5	_	6	ns
			4.5 to 5.5	0.5	_	5.5	ns
t _{PZH} /t _{PZL}	3-state output enable	see Figs 7 and 8	1.65 to 1.95	1.0	_	12	ns
	time input OE to Y		2.3 to 2.7	0.5	_	8.5	ns
			2.7	0.5	_	8.5	ns
			3.0 to 3.6	0.5	-	7	ns
			4.5 to 5.5	0.5	_	6.5	ns
t _{PHZ} /t _{PLZ}	3-state output disable	see Figs 7 and 8	1.65 to 1.95	1.0	_	12	ns
	time input OE to Y		2.3 to 2.7	0.5	_	6.5	ns
			2.7	0.5	_	6.5	ns
			3.0 to 3.6	0.5	_	6.5	ns
			4.5 to 5.5	0.5	_	5.5	ns

Bus buffer/line driver; 3-state

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AC WAVEFORMS



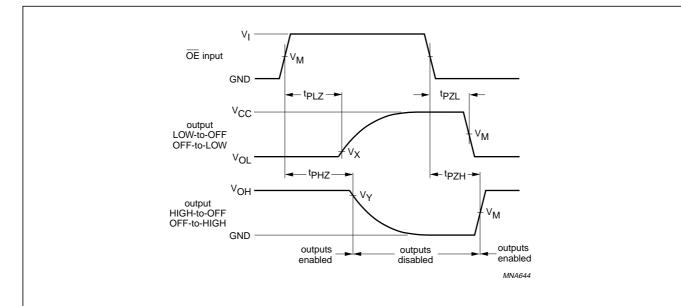
V	V	INPUT		
V _{CC}	V _M	VI	$t_r = t_f$	
1.65 V to 1.95 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns	
2.3 V to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns	
2.7 V	1.5 V	2.7 V	≤ 2.5 ns	
3.0 V to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns	
4.5 V to 5.5 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.5 ns	

 V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.6 Input A to output Y propagation delay times.

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V _{CC}	V	INPUT		
V CC	; V _M		$t_r = t_f$	
1.65 V to 1.95 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns	
2.3 V to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns	
2.7 V	1.5 V	2.7 V	≤ 2.5 ns	
3.0 V to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns	
4.5 V to 5.5 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.5 ns	

$$\begin{split} V_X &= V_{OL} + 0.3 \text{ V at } V_{CC} \geq 2.7 \text{ V}; \\ V_X &= V_{OL} + 0.15 \text{ V at } V_{CC} < 2.7 \text{ V}; \end{split}$$

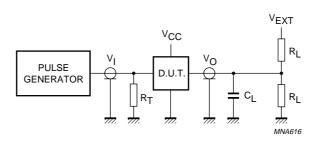
$$\begin{split} &V_Y = V_{OH} - 0.3 \text{ V at } V_{CC} \geq 2.7 \text{ V}; \\ &V_Y = V_{OH} - 0.15 \text{ V at } V_{CC} < 2.7 \text{ V}. \end{split}$$

 $\mbox{V}_{\mbox{\scriptsize OL}}$ and $\mbox{V}_{\mbox{\scriptsize OH}}$ are typical output voltage drop that occur with the output load.

Fig.7 3-state enable and disable times.

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V _{z-z}	V _I C _L		C. B.		V _{EXT}		
V _{CC}	"	CL	R_L	t _{PLH} /t _{PHL}	t _{PZH} /t _{PHZ}	t _{PZL} /t _{PLZ}	
1.65 V to 1.95 V	V _{CC}	30 pF	1 kΩ	open	GND	$2 \times V_{CC}$	
2.3 V to 2.7 V	V _{CC}	30 pF	500 Ω	open	GND	$2 \times V_{CC}$	
2.7 V	2.7 V	50 pF	500 Ω	open	GND	6 V	
3.0 V to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	6 V	
4.5 V to 5.5 V	V _{CC}	50 pF	500 Ω	open	GND	$2 \times V_{CC}$	

Definitions for test circuits:

R_L = Load resistor.

 C_L = Load capacitance including jig and probe capacitance.

 $R_{T}\!=\!Termination$ resistance should be equal to the output impedance Z_{o} of the pulse generator.

Fig.8 Load circuitry for switching times.

Product specification Philips Semiconductors

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PACKAGE OUTLINES

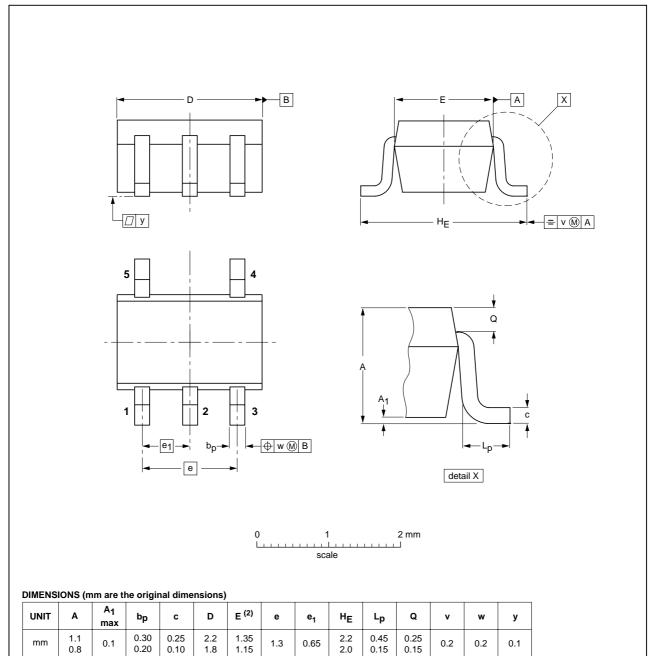
mm

0.1

0.20

Plastic surface mounted package; 5 leads

SOT353



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT353			SC-88A			97-02-28

0.65

0.2

0.2

0.1

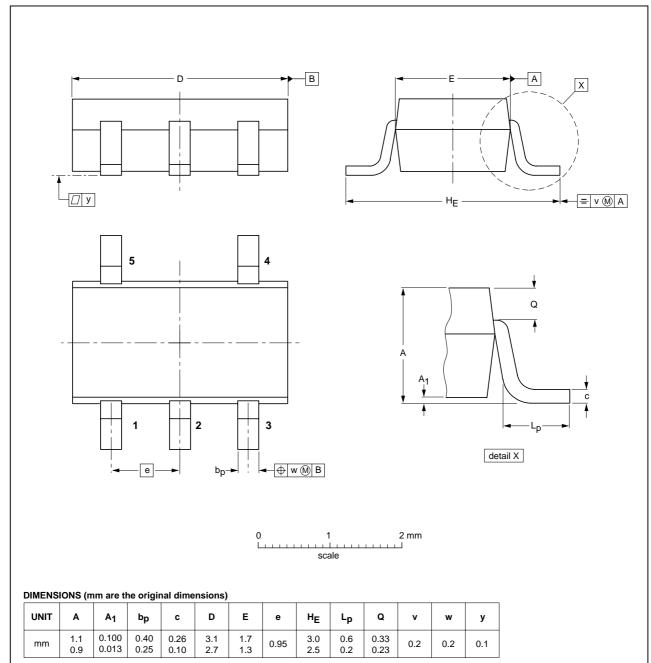
1.3

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Plastic surface mounted package; 5 leads

SOT753

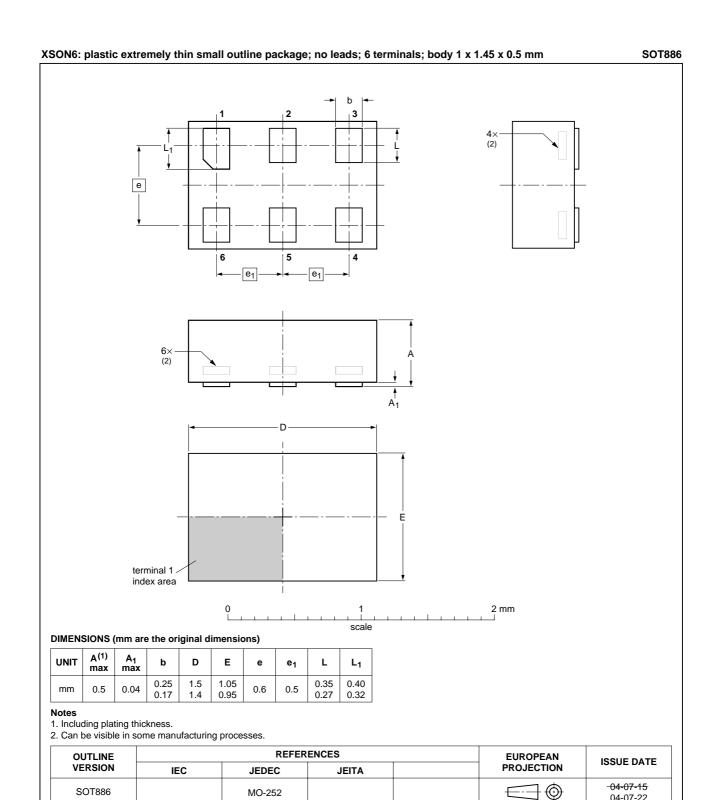


OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT753			SC-74A			02-04-16

Bus buffer/line driver; 3-state

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04-07-22



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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